

SV7330SE

8KV ESD, Low Ron, Ultra-Wide Bandwidth, Low Power, Quad SPDT Video Switch

> v0.97a SAVITECH Corporation

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Features

- Seamless Bidirectional Data Switching
- Roboust ESD protection: HBM 8KV
- Low Turn-On Resistance: 4.5Ω (V_{CC}=5V)
- Wide Bandwidth: -3dB BW = 550MHz
- High Off Isolation: –60dB
- Extreme Low Power Consumption: 0.4uA
- Single Vcc Supply: +1.8V ~ +5V
- Vcc Supply Accuracy: +/-10%
- Control Input Pins are compatible with TTL and 5V/3.3V CMOS
- Pb-free & Green Package: QSOP-16, SOP-16, TSSOP-16

Description

The SV7330SE is a high quality, low power, highspeed analog video switch. It features wide bandwidth, low turn-on resistance and low crosstalk that make it ideal for seamless composite and RGB SD and HD video switching applications

It can also function as a 4-bit 1-of-2 MUX/DEMUX for other high-speed data switching applications. A single switch-enable (\overline{EN}) input is used to enable or disable the switch. When \overline{EN} is set at logic 'L', the D-port is connected to the S-port that shows low-Ron between D-port and S-port that enables the switch. When \overline{EN} is set at logic 'H', the highimpedance state exists between the D and S ports that disable the switch. The select (IN) pin controls the input data path of the MUX/DEMUX. The device spec at high off- isolation, so it will maintain isolation during power down.

It is powered by a single +1.8 to +5V rail typically and consumes extremely low power.

Pin connection



QSOP-16/SOP-16/TSSOP-16

Pin Description

PIN	DESCRIPTION
S1,S2	Analog video I/Os
D	Analog video
IN	IN Select input
ĒN	Switch-enable input

Function Table

INPUTS		INPUT/OUTPUT	EUNCTION		
EN	IN	D	FUNCTION		
L	L	S1	D port = S1 port		
L	Н	S2	D port = S2 port		
Н	Х	Z	Disconnected		

Ordering Information

Ordering Code	Operation Range	Package	Packing
SV7330SE-16QP-TR2	-40°C ~ +85°C	QSOP-16L	Tape & Reel, 2500pcs
SV7330SE-16SP-TR2	-40°C ~ +85°C	SOP-16	Tape & Reel, 2500pcs
SV7330SE-16TP-TR3	-40°C ~ +85°C	TSSOP-16	Tape & Reel, 3000pcs
Note: <u>SV</u> 7330S ↓ ↓ SAVITECH Part Nur	E - <u>16QP</u> - ↓ nber Package S 16QP: QSOP-16L T 16SP: SOP-16 T 16TP: TSSOP-16	TR2 ↓ Shipping TR2: Tape & Reel, 2500pcs TR3: Tape & Reel, 3000pcs	

Function Diagram



Absolute maximum ratings

Parameter	Value	Unit
V _{CC} to GND, Supply Voltage,	7	V
Input Voltage	GND - 0.3 to (V _{CC}) +0.3	V
Storage Temperature Range	-65 to +150	°C
Continuous current through V_{DD} or GND	100	mA
ESD Susceptibility: HBM	>8000	V
ESD Susceptibility: MM	400	V

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

CAUTION

This integrated circuit can be damaged by ESD if you don't pay attention to ESD protection. SAVITECH recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

Electrical characteristics

(V_{CC} = +4.5V, GND = 0V, T_A = +25°C unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MIN	ТҮР	МАХ	UNITS	
DC CHARACTERISTICS							
		V _{CC} =4.5V, Vin=0V, I _D =26mA		6.5		Ω	
On-Resistance	R _{on}	V_{CC} =4.5V, Vin=2V, I _D =26mA	V _{CC} =4.5V, Vin=2V, I _D =26mA			Ω	
		V_{CC} =4.5V, Vin=4.5V, I _D =26mA		19		Ω	
Input High Voltage	V _{IH}	V _{CC} =5.0V	V _{DD} * 0.6	2.34	V _{DD} * 0.4	V	
Input Low Voltage	V _{IL}	V _{CC} =5.0V		2.33	0.5	V	
Input High Current	Цн	$V_{\rm CC}$ = 5.5V, $V_{\rm IN}$ and $V_{\rm EN}$ = $V_{\rm CC}$		±1	2.5	μA	
Input Low Current	I _{IL}	$V_{\rm CC}$ = 5.5V, $V_{\rm IN}$ and $V_{\rm EN}$ = 0V		±1	2.5	μA	
Analog Output Leakage Current	Ι _ο	V_{CC} = 5.5V, V_{S1} or V_{S2} = 0.3V/1.2V, V_D = 1.2V/0.3V		±1		μA	
Clamp Diode Voltage	V _{IK}	I _{IN} = -1.8mA		-0.78		V	
DYNAMIC CHARACTERISTIC	S	•					
Turn-On Time	T _{ON}			22		ns	
Turn-Off Time	T _{OFF}	- KL= 750, CL= 20PF		4.8		ns	
Officialition	O _{lso}	Sync in 1080i 60Hz schema, DC couple		-60.8		dB	
		2T pulse in 1080i 60Hz schema, DC couple		-59.0		dB	
Channel- to Channel Crosstalk	X _{TALK}	f = 10MHz		-66.0		dB	
–3dB Bandwidth	BW			550		MHz	
Input/Enable Capacitance	C _{IN}	f = 1MHz		4		pF	
Differential Gain	D_G	V _{cc} =5.0V, 5 Step Modulation Pattern in PAL schema		0.64		% p-p	
Differential Phase	D _P	V _{cc} =5.0V, 5 Step Modulation Pattern in PAL schema		0.15		% deg.	
POWER REQUIREMENTS							
Power Supply Current	lcc	V_{CC} = 5.5V, V_{IN} = 0V or V_{CC}		0.4	3	μA	
Supply Current per Input @ TTL HIGH	ΔI_{CC}	V _{CC} = 5.5V, V _{IN} = 3.4V			2.5	mA	

Specifications are subject to change without notice.

PARAMETER	DESCRIPTION
Ron	Resistance between source and drain with switch in the ON state
lo	Output leakage current measured at S1, S2, and D with the switch OFF
Vin	Digital voltage at the IN pin that selects between S1 and S2 analog inputs
Vı	Voltage applied to the D or S1, S2 pins when D or S1, S2 is the switch input
Vıк	A Clamp Diode Voltage Drop
Cin	Capacitance at the digital inputs
Coff	Capacitance at analog I/O (S1, S2, D) with switch OFF
Сол	Capacitance at analog I/O (S1, S2, D) with switch ON
Viн	Minimum input voltage for logic HIGH
VIL	Minimum input voltage for logic LOW
Іін (іс)	Input current of the digital input
Τον	Propagation delay measured between 50% of the digital input to 90% of the analog output when switch is turned ON.
Тоғғ	Propagation delay measured between 50% of the digital input to 90% of the analog output when switch is turned OFF.
BW	response of the switch in the ON state measured at 3dB down
Dg	Magnitude variation between analog input and output pins when the switch is ON and the dc offset of composite-video signal varies at the analog input pin. In the PAL standard, the frequency of the video signal is 4.43MHz.
Dr	Phase variation between analog input and output pins when the switch is ON and the dc offset of composite-video signal varies at the analog input pin. In the PAL standard, the frequency of the video signal is 4.43MHz.
Oiso	Off isolation is the resistance (measured in 100IRE 2T 1080i pulse) between the input and output with the switch off (NO)

Typical Performance Characteristics

DC ELECTRICAL CHARACTERISTICS







Clamp Diode Voltage (VIK)



Control Input Leakage (I_{IH} and I_{IL}) for $\overline{S0},\,\overline{S1},\,E_A\,\text{and}\,E_B$



IO Input Leakage (I_O) for IAn, IBn, Y_{A} and Y_{B}



Switch ON Resistance (R_{ON})



Input Logic Level (V_{IH}, V_{IL})



AC ELECTRICAL CHARACTERISTICS

Turn ON/ Turn OFF Timing (T_{ON}, T_{OFF})



Bandwidth (-3dB Bandwidth, BW)



Differential Gain/ Phase (D_G , D_P)





Video Off-Isolation (OISO): Sync Feed Through



Video Off-Isolation (OISO): 2T Pulse Feed Through



Parameter Measurement Information





Off-State Leakage Current (I_o)



On-State Leakage Current (Io)



Clamp Diode Voltage (VIK)



Rail to Rail Turn ON/Turn-OFF Timing (Ton, Toff)



Bandwidth (BW)



Differential Gain/ Phase (D_G, D_P)



DC Couple Sync/ Pulse Feed-Through (Off-Isolation, O_{ISO})



QSOP-16 MECHANICAL DATA









Note:

- 1. Dimension 0 does not include mold protrusions or
- gate burrs Mold protrusions and gate burrs shall not exceed 0.006 inch per side. 2.

Currence al	Dimension in MM			Dimension in Inch		
Symbol	Min.	Nom.	Max.	Min.	Nom.	Max.
А	1.35	1.63	1.75	0.053	0.064	0.069
A1	0.10	0.15	0.25	0.004	0.006	0.010
A2			1.50			0.059
b	0.20		0.30	0.008		0.012
С	0.18		0.25	0.007		0.010
е	0.0	650 BASI	С	0	.025 BASI	EC
D	4.80	4.90	5.00	0.189	0.193	0.197
Е	5.79	5.99	6.20	0.228	0.236	0.244
E1	3.81	3.961	3.99	0.150	0.154	0.157
L	0.41	0.635	1.27	0.016	0.025	0.050
h	0.25		0.50	0.010		0.020
L1	0.254 BASIC			0.010 BASIC		
ZD	0	.229 REF		0.009 REF		
R1	0.20		0.33	0.008		0.013
R	0.20			0.008		
Θ	0*		8*	0*		8*
Θ1	0*			0*		
Θ2	5*	10*	15*	5*	10*	15*
JEDEC	MO-137 (AB)					

SOP-16 MECHANICAL DATA





0 set et	Dimension in MM			Dimension in Inch		
Symbol	Min.	Nom.	Max.	Min.	Nom.	Max.
А	1.35	1.60	1.75	0.053	0.063	0.069
A1	0.10		0.25	0.004		0.010
A2		1.45			0.057	
В	0.33		0.51	0.013		0.020
С	0.19		0.25	0.007		0.010
D	9.80		10.00	0.386		0.394
E1	3.80	3.90	4.00	0.150		0.157
е		1.27				
E	5.80	6.00	3.20	0.228		0.244
L	0.40		1.27	0.016		0.050
у			0.10			0.004
Θ	0°		8°	0°		8°
L1-L1'			0.12			0.005
L1	1.04REF		0.041REF		=	



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